

~ž#&%"50" ' 1#

Silicon PNP transistor in a SOT-23 Plastic Package.

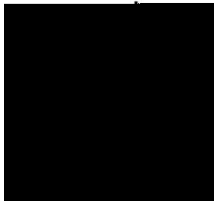
+ž.06%ž#

Complementary pair with L8050M.

155-&.0" ' 1#

Power amplifier applications.

Ł76"!.-ž10, "%&6"0



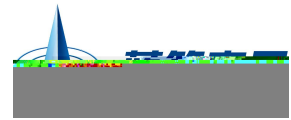
8"11"14



PIN1 Base PIN 2 Emitter PIN 3 Collector

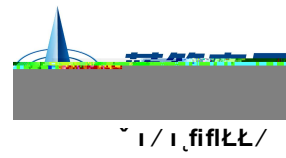
*+Ł, -.##/"&.0" ' 1# 2, ~. %3"14

h_{FE}



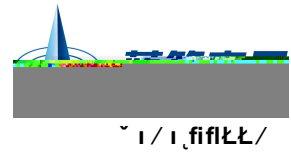
Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	-30	V
Collector to Emitter Voltage	V_{CEO}	-20	V
Emitter to Base Voltage	V_{EBO}	-6.0	V
Collector Current - Continuous	I_C	-1.5	A
Base Current - Continuous	I_B	-0.5	A
Collector Po/	Dissi	o	n

2.0mA



3"14B1#0%6&0"1#





> 温度曲线 Temperature Profile for IR Reflow Soldering(Pb-Free)

说明：

- 1、预热温度 150~180 ，时间 60~90sec;
- 2、峰值温度 245±5 ，时间持续为 5±0.5sec;

Note:

- 1.Preheating:150~180°C, Time:60~90sec.
- 2.Peak Temp.:245